

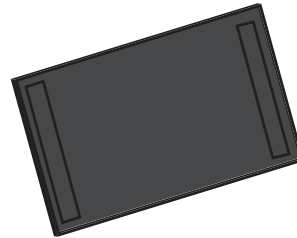
Extreme Temperature Silicon Capacitor

XTSC1206 1μF
935.133.427.710

The IPDiA Technology features a Capacitor Integration Capability (up to 250nF/mm²) which allows a capacitance value similar to X8R dielectric, but with better electrical performances than C0G/NP0 dielectrics.

This technology also offers high reliability, up to 10 times better than alternative capacitor technologies.

This silicon based technology is RoHS compliant and compatible with lead free reflow soldering process.



Key Applications

- 250°C Requirements, High Temperature Applications, such as Military, Aerospace, Automotive & Downhole Industries.
- High Reliability Applications
- Decoupling / Filtering / Charge Pump (ie. Pressure Sensor, Motor Management)
- Replacement of X8R and C0G Dielectrics
- Downsizing

Key Features

- Ultra Low Profile (100μm)
- Ultra High Temperature up to 250°C;
 - Temperature Coeff < ±1.5% (-55 to +250°C)
 - Voltage < 0.1 % / V
 - Negligible Capacitance Loss through Ageing
- Unique High Capacitance in EIA/0402 Package Size, up to 100nF
- High Reliability (FIT < 0.017 parts / billion hours)
- Low Leakage Current down to 100pA
- Low ESL and Low ESR
- Suitable with Lead Free Reflow-Soldering

Part Number

| | | | | |
|--|--|---|--|-------------------|
| 935.132. | B. 2 | S. | U. | XX |
| ie. 47nF/0402 case (XTSC type) → 935.133.424.547 | ↓ Breakdown Voltage: 4 = 11V 7 = 30V | ↓ Size: 2 = 1005 3 = 0201 4 = 0402 | ↓ Unit: 0 = 10f 5 = 1n 1 = 0.1p 6 = 10n 2 = 1p 7 = 0.1u 3 = 10p 8 = 1u 4 = 0.1n 9 = 10u | ↓ Value |

| Parameters | Value |
|----------------------------------|---|
| Capacitance Range | 100pF to 100nF |
| Capacitance Tolerances | ±15% |
| Operating Temperature Range | -55°C to 250°C |
| Storage Temperatures | -70°C to 265°C |
| Temperature Coefficient | <±1.5%, from -55°C to +250°C |
| Breakdown Voltage (BV) | 11VDC, 30VDC |
| Capacitance Variation Vs. RVDC | 0.1% / V (from 0V to RVDC) |
| Equivalent Serial Inductor (ESL) | Max 100pH |
| Equivalent Serial Resistor (ESR) | Max 400mΩ |
| Insulation Resistance | 50GΩ min @ 3V, 25°C 10GΩ min @ 3V, 250°C |
| Ageing | Negligible, < 0.001% / 1000h |
| Reliability | FIT < 0.017 parts / billion hours |
| Capacitor Height | Max 400μm |